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# Efficient charge separation promoting visible-light-driven photocatalytic activity of $MnO_x$ decorated $WS_2$ hybrid nanosheets



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#### 1. Introduction

Since the first report on photocatalytic (PC) water splitting by TiO<sub>2</sub> under ultraviolet light [1,2], solar photocatalysis for remediation of environmental pollutants and hydrogen production from water has attracted a tremendous amount of interest as it offers direct use of sunlight for energy and environmental applications [3–8]. As one of typical materials in transition metal dichalcogenides allotrope, tungsten disulfide (WS<sub>2</sub>) shows a unique combination of valuable structural, electronic, optical, mechanical, chemical, and thermal properties that have been studied for decades [9–15]. The bandgap of WS<sub>2</sub> is ~1.35 eV, which expands the light absorption region to ~910 nm, completely covering the visible region of solar spectrum [10,16]. Furthermore, the valence and conduction band edges of WS<sub>2</sub> are suitable to drive the necessary redox chemistry for photocatalysis [7,10,12,16,17]. However, the narrow bandgap of WS<sub>2</sub> will inevitably cause high recombination of photo-induced electrons and holes, retarding its PC activity. Therefore, efficient charge separation for advancing the PC activity of WS<sub>2</sub> becomes a key issue.

Recent investigations on manganese oxide ( $MnO_x$ ) anchored to Bibased photocatalysts (such as BiVO<sub>4</sub> and BiOI) have shown that  $MnO_x$ as active/reaction sites can provide trapping sites for the photogenerated holes to inhibit carrier recombination [18–20]. As such, utilizing the decoration with  $MnO_x$  could be a suitable approach

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#### ABSTRACT

Tungsten disulfide (WS<sub>2</sub>) has recently emerged as a narrow-band visible-light-driven photocatalyst; however, high recombination of photo-induced electrons and holes becomes a major concern to advance its photocatalytic performance. Here we for the first time adopt manganese oxide (MnO<sub>x</sub>) as a hole-trapping material to decorate WS<sub>2</sub> nanosheets by photo-deposition in MnSO<sub>4</sub> solution. The MnO<sub>x</sub> decorated WS<sub>2</sub> (MnO<sub>x</sub>/WS<sub>2</sub>) is found to exhibit more negative flat band potential, lower impedance and higher photocurrent response compared with pure WS<sub>2</sub>. These features beneficial to charge transfer and separation render the MnO<sub>x</sub>/WS<sub>2</sub> nanosheets highly active and visible-light-driven photocatalyst in RhB degradation. Further, the hole-trapping function of MnO<sub>x</sub> in promoting efficient charge separation of MnO<sub>x</sub>/WS<sub>2</sub> is experimentally demonstrated.

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to promote the separation efficiency of photo-induced charge carriers of  $WS_2$ , which has yet to be reported until now.

In this communication, we for the first time use MnO<sub>x</sub> as a hole-trapping material to promote the charge separation efficiency of WS<sub>2</sub>. MnO<sub>x</sub> decorated WS<sub>2</sub> (MnO<sub>x</sub>/WS<sub>2</sub>) hybrid nanosheets were prepared by photo-deposition in MnSO<sub>4</sub> solution, and characterized by scanning electron microscope (SEM), energy-dispersive spectroscopy (EDS), Xray photoelectron spectroscopy (XPS), Mott-Schottky (M-S) analysis, electrochemical impedance spectroscopy (EIS) and amperometric i-t curve. We find that MnOx/WS2 exhibits more negative flat band potential (E<sub>fb</sub>), lower impedance, and higher photocurrent response compared with pristine WS<sub>2</sub>. Herein, rhodamine B (RhB), a nonbiodegradable xanthane dve in the aqueous ecosystem, was chosen as a representative probe to evaluate the photocatalytic activity of the as-obtained MnO<sub>x</sub>/WS<sub>2</sub> nanosheets. As a result, the visible-light-driven PC activity of MnO<sub>x</sub>/WS<sub>2</sub> is significantly enhanced. Furthermore, the hole-trapping function of MnO<sub>x</sub> in promoting efficient charge separation of WS<sub>2</sub>, which consequently boosts the PC activity, has also been demonstrated.

#### 2. Experimental

The MnO<sub>x</sub>/WS<sub>2</sub> hybrid nanosheets were prepared by photo-deposition. Typically, 1 g WS<sub>2</sub> (Aladdin, 99.9%) and 50 mg MnSO<sub>4</sub> (Tianjin Fuchen, AR) were mixed in 100 mL deionized water. The suspension was then irradiated by a 300 W Xe lamp (CEL-HXF300) under continuous stirring. After 5 h of photo-deposition, the suspension was centrifuged and rinsed, followed by drying at 60 °C overnight. The black  $MnO_x/WS_2$  powder was obtained. For the  $MnO_x/WS_2$  film, a slurry

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containing 1 g WS<sub>2</sub> and 1.5 mL terpineol in an ethanol solution was prepared via rotary evaporation and subsequently coated on a fluorinedoped tin oxide (FTO) glass substrate via a typical doctor blading method. The decoration of  $MnO_x$  on the WS<sub>2</sub> film follows the photo-deposition procedure similar to  $MnO_x/WS_2$  powder.

Electrochemical and photoelectrochemical measurements were carried out on an electrochemical workstation (CHI660C, ShangHai) in a three-electrode system, using 0.5 M Na<sub>2</sub>SO<sub>4</sub> solution as the electrolyte. A 300 W Xe lamp with a 420 nm cut-off was used to guarantee irradiation only by visible light. The light intensity at the electrode surface is determined as ~250 mW/cm<sup>2</sup>. The PC activity was evaluated by decomposition of RhB aqueous solution (initial concentration of RhB =  $1 \times 10^{-5}$  mol/L, photocatalyst amount = 50 mg, and total volume = 50 mL) under visible light irradiation. Analytical grade RhB was purchased from Tianjin Fu Chen Chemicals Co. Photoelectrocatalysis was carried out in the three-electrode system using a 2.5 × 3 cm<sup>2</sup> photocatalyst film at a bias potential of -0.5 V vs SCE. Triethanolamine (TEOA, 1 mL) as trapping reagent was used to detect the generation of active holes in the PEC process.

#### 3. Results and discussion

The photo-deposition of MnO<sub>x</sub> on the surface of WS<sub>2</sub> was carried out using MnSO<sub>4</sub> as a precursor and water as an electron scavenger. Under photo-irradiation the photogenerated holes on WS<sub>2</sub> are readily available for the photo-oxidation of Mn<sup>2+</sup> into MnO<sub>x</sub> accompanying the elimination of photogenerated electrons by water scavenger. Similar mechanisms have also been reported in MnOx modified BiVO4 or BiOI [18-20]. The SEM images in Fig. 1a&b show the morphological features of WS<sub>2</sub> and MnO<sub>x</sub>/WS<sub>2</sub>. WS<sub>2</sub> displays a hexagonal nanosheet structure in shape (Fig. 1a). For MnO<sub>x</sub>/WS<sub>2</sub>, the hexagonal nanosheet structural feature remains constant except for MnO<sub>x</sub> nanoparticles dispersed on the surface of WS<sub>2</sub> nanosheets (Fig. 1b). The EDS spectrum of  $MnO_x/$ WS<sub>2</sub> exhibits the peaks related to elemental W, S, O and Mn (Fig. 1c). The atomic content of Mn in the hybrid MnOx/WS<sub>2</sub> sample is measured as ~1 at.%. The surface chemical composition and chemical valence state of the elements in MnO<sub>x</sub>/WS<sub>2</sub> are checked by XPS (Fig. 1d-f). Peaks located at 33.1, 35.3, and 38.7 eV are ascribed to W  $4f_{7/2}$ , W  $4f_{5/2}$ , and W  $5p_{5/2}$ , respectively (Fig. 1d). The peaks of S  $2p_{3/2}$  and S  $2p_{1/2}$  orbital of divalent sulfide ions are observed at 162.9 and 164.0 eV, respectively (Fig. 1e). The bonding energy of the elements is consistent with the  $W^{4+}$  and  $S^{2-}$  in WS<sub>2</sub> [16]. The two peaks of the Mn 2p region at 641.8 and 654.2 eV are assigned to Mn 2p<sub>3/2</sub> and Mn 2p<sub>1/2</sub>, respectively, as shown in Fig. 1f. Based on their binding energies, it can be reasonably concluded that  $MnO_x$  forms on the surface of WS<sub>2</sub> [18,20].

Fig. 2a shows the M-S plots of  $WS_2$  and  $MnO_x/WS_2$ . According to the M-S equation:

$$1/C_{sc}^2 = 2(E - E_{fb} - \kappa T/e)/(e\epsilon\epsilon_0 N_D)$$

where C<sub>sc</sub> is the total capacitance of the space charge region, E is potential,  $E_{fb}$  is the flat band potential,  $\kappa$  is Boltzmann's constant, T is temperature,  $\varepsilon$  is permittivity in vacuum,  $\varepsilon_0$  is dielectric constant, N<sub>D</sub> is charge carrier density. The negative slopes of the two lines show that both WS<sub>2</sub> and MnO<sub>x</sub>/WS<sub>2</sub> are n-type semiconductor [21,22]. N<sub>D</sub> was calculated according to the linear slope of the M-S plot, and it turns out to be larger for MnO<sub>x</sub>/WS<sub>2</sub> film  $(5.6 \times 10^{19} \text{ cm}^{-3})$  in comparison with pure WS<sub>2</sub> film  $(3.6 \times 10^{19} \text{ cm}^{-3})$ . The results indicate that the presence of MnO<sub>2</sub> leads to an increase in the number of charge carriers, which have a positive effect in lowering the charge transfer resistance. The Eff. of WS<sub>2</sub> and MnO<sub>x</sub>/WS<sub>2</sub> calculated according to the intercept with the potential axis are -0.68 V (vs SCE) and -0.78 V (vs SCE), respectively. It is found that after MnO<sub>x</sub>-decorating, the value of E<sub>fb</sub> shifts negatively. As for the ntype WS<sub>2</sub> semiconductor, negative shift of E<sub>fb</sub> causes the increase of upward band bending i.e. the enhancement of the near-surface electric field in the bent-band region, and finally facilitating the effective separation of electron-hole pairs [23]. Apparently, MnO<sub>x</sub>-decorating enhances the charge transfer and separation ability of  $MnO_x/WS_2$ .

It is well established that EIS Nyquist plots are associated with charge transfer resistance [21,24]. The radius of the arc in the EIS spectra reflects the interface layer resistance occurring at the electrode surface, and a smaller arc radius implies a lower charge transfer resistance [25]. A remarkable decrease in Nyquist plots arc radius for MnO<sub>x</sub>/WS<sub>2</sub> is observed (Fig. 2b), which suggests that charge transfer resistance of MnO<sub>x</sub>/WS<sub>2</sub> is much smaller than that of pure WS<sub>2</sub>. Note that the reduction of charge transfer resistance is believed to be beneficial to efficient charge separation [26,27].

Moreover, transient photocurrent responses of the  $MnO_x/WS_2$  photocatalyst can directly correlate with the separation efficiency of the photogenerated carriers [20,26,28]. Fig. 2c presents the results of transient photocurrent responses obtained from the  $MnO_x/WS_2$  and pure  $WS_2$  films. The photocurrent generates when the light is on and decreases to zero when the light is turned off. It is clear that the photocurrent of  $MnO_x/WS_2$  is obviously larger than that of pure  $WS_2$ . The enhanced photocurrent activity of  $MnO_x/WS_2$  indicates more efficient separation of photo-induced electron-hole pairs in  $MnO_x/WS_2$  than in



Fig. 1. (a, b) SEM images of WS<sub>2</sub> (a) and MnO<sub>x</sub>/WS<sub>2</sub> (b), inset of (a) and (b) are the magnified SEM images of WS<sub>2</sub> and MnO<sub>x</sub>/WS<sub>2</sub> respectively. (c) EDS spectrum of MnO<sub>x</sub>/WS<sub>2</sub>. (d-f) XPS scan of W 5p and W 4f (d), S 2p (e), and Mn 2p (f) for MnO<sub>x</sub>/WS<sub>2</sub>.

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